

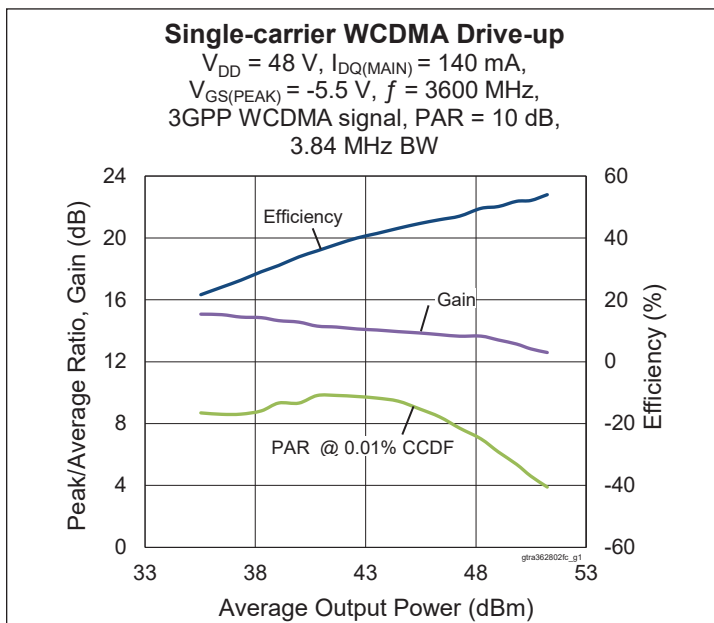
GTRA362802FC

Thermally-Enhanced High Power RF GaN on SiC HEMT 280 W, 48 V, 3400 – 3600 MHz

Description

The GTRA362802FC is a 280-watt (P_{3dB}) GaN on SiC high electron mobility transistor (HEMT) designed for use in multi-standard cellular power amplifier applications. It features input matching, high efficiency, and a thermally-enhanced package with earless flange.

GTRA362802FC
Package H-37248C-4



Features

- GaN on SiC HEMT technology
- Input matched
- Asymmetrical Doherty design
 - Main: $P_{3dB} = 120\text{ W Typ}$
 - Peak: $P_{3dB} = 180\text{ W Typ}$
- Typical Pulsed CW performance, 3400 – 3600 MHz, 48 V, combined outputs, 10 μs pulse width, 10% duty cycle
 - Output power at $P_{3dB} = 280\text{ W}$
 - Drain Efficiency = 60%
 - Gain = 15 dB
- Capable of handling 10:1 VSWR @ 48 V, 44 W (CW) output power
- Human Body Model Class 1A (per ANSI/ESDA/ JEDEC JS-001)
- Low thermal resistance
- Pb-free and RoHS compliant

RF Characteristics

Single-carrier WCDMA Specifications (tested in Wolfspeed Doherty production test fixture)

$V_{DD} = 48\text{ V}$, $I_{DQ} = 140\text{ mA}$, $P_{OUT} = 44\text{ W avg}$, $V_{GS(peak)} = V_{GS} @ I_{DQ} = 200\text{ mA} - 2.2\text{ V}$, $f = 3600\text{ MHz}$, 3GPP signal, channel bandwidth = 3.84 MHz, peak/average = 10 dB @ 0.01% CCDF

Characteristic	Symbol	Min	Typ	Max	Unit
Linear Gain	G_{ps}	12	13.5	—	dB
Drain Efficiency	η_D	42.5	45.5	—	%
Adjacent Channel Power Ratio	ACPR	—	-29.5	-26.5	dBc
Output PAR @ 0.01% CCDF	OPAR	5.4	6.5	—	dB

All published data at $T_{CASE} = 25^\circ\text{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

DC Characteristics

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-source Breakdown Voltage (main)	$V_{GS} = -8\text{ V}, I_D = 10\text{ mA}$	$V_{(BR)DSS}$	150	—	—	V
	(peak) $V_{GS} = -8\text{ V}, I_D = 10\text{ mA}$	$V_{(BR)DSS}$	150	—	—	V
Drain-source Leakage Current	$V_{GS} = -8\text{ V}, V_{DS} = 10\text{ V}$	I_{DSS}	—	—	7	mA
Gate Threshold Voltage (main)	$V_{DS} = 10\text{ V}, I_D = 14.4\text{ mA}$	$V_{GS(th)}$	-3.8	-3.0	-2.3	V
	(peak) $V_{DS} = 10\text{ V}, I_D = 21.6\text{ mA}$	$V_{GS(th)}$	-3.8	-3.0	-2.3	V

Recommended Operating Conditions

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Drain Operating Voltage		V_{DD}	0	—	50	V
Gate Quiescent Voltage	$V_{DS} = 48\text{ V}, I_D = 140\text{ mA}$	$V_{GS(Q)}$	-3.5	-3	-2.4	V

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source Voltage	V_{DSS}	125	V
Gate-source Voltage	V_{GS}	-10 to +2	V
Operating Voltage	V_{DD}	55	V
Gate Current (main)	I_G	14.4	mA
	(peak) I_G	21.6	mA
Drain Current (main)	I_D	5.4	A
	(peak) I_D	8.1	A
Junction Temperature	T_J	225	°C
Storage Temperature Range	T_{STG}	-65 to +150	°C

Operation above the maximum values listed here may cause permanent damage. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the component. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. For reliable continuous operation, the device should be operated within the operating voltage range (V_{DD}) specified above.

Thermal Characteristics

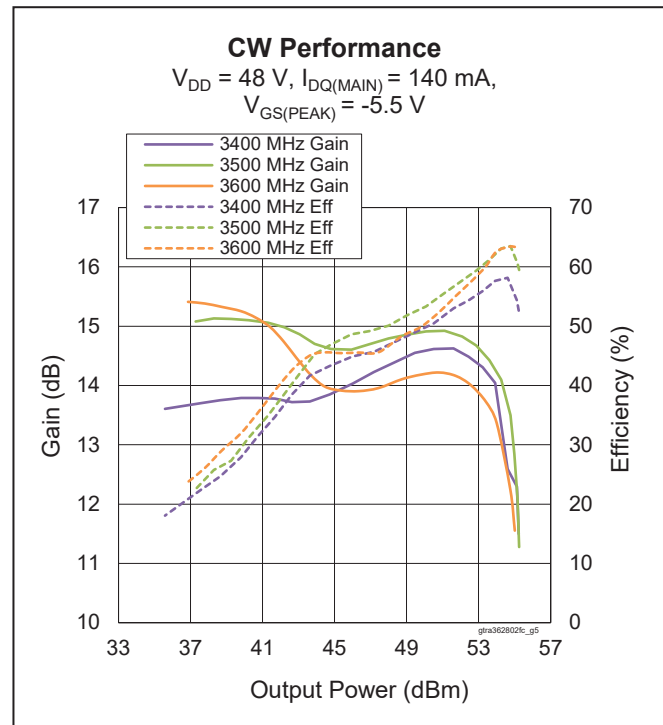
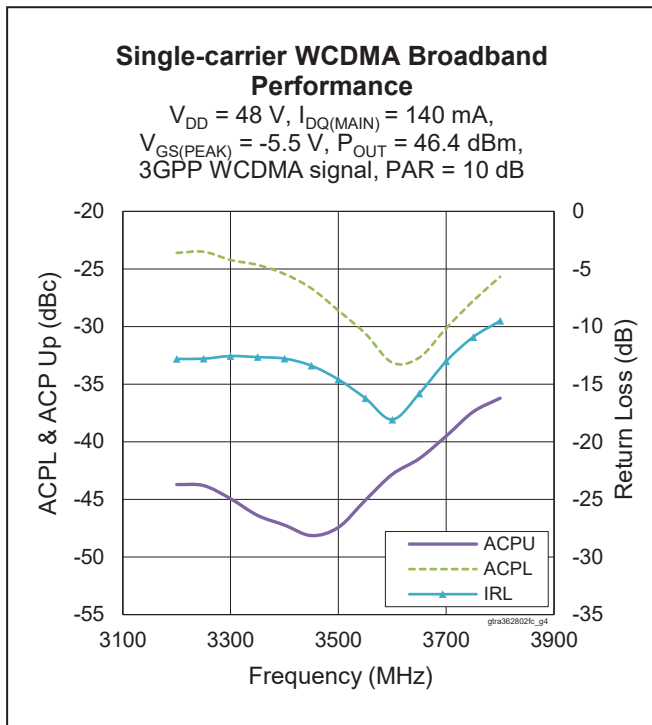
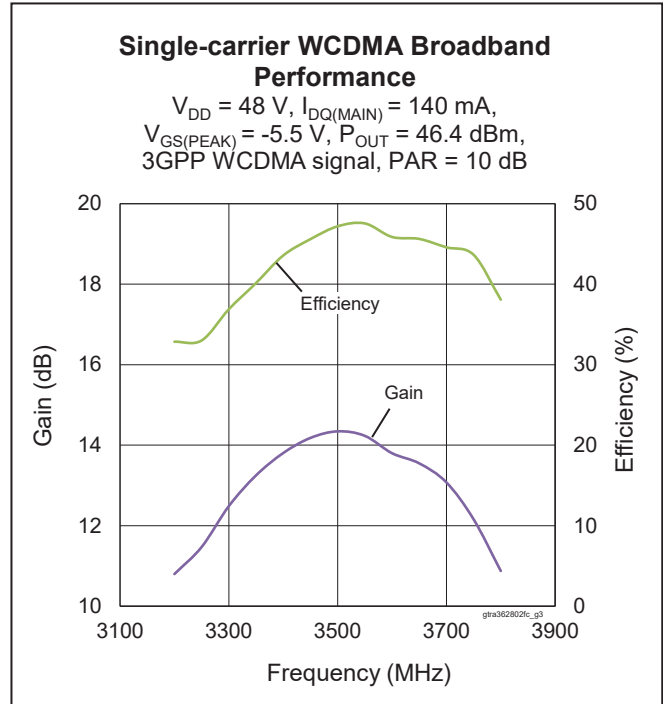
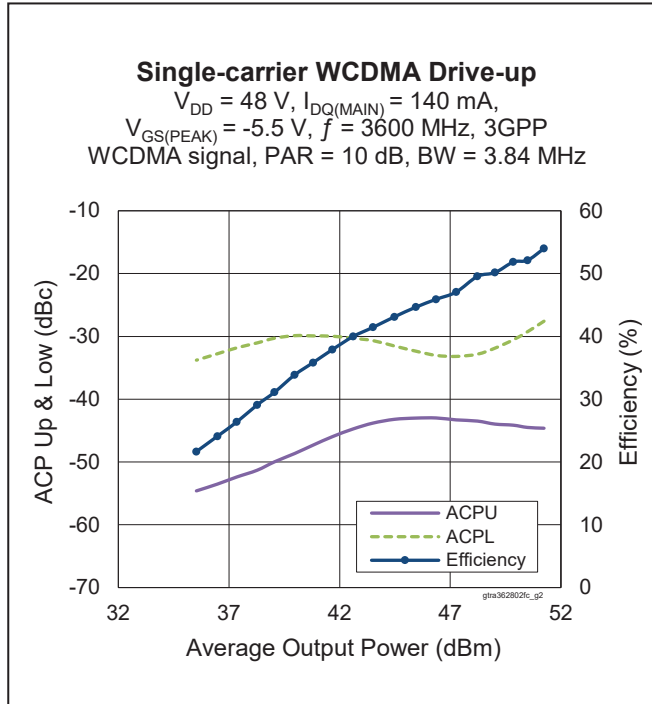
Parameter	Symbol	Value	Unit
Thermal Resistance (main, $T_{CASE} = 70\text{ °C}, 67\text{ W DC}$)	$R_{\theta JC}$	2.2	°C/W
	(peak, $T_{CASE} = 70\text{ °C}, 100\text{ W DC}$) $R_{\theta JC}$	1.5	°C/W



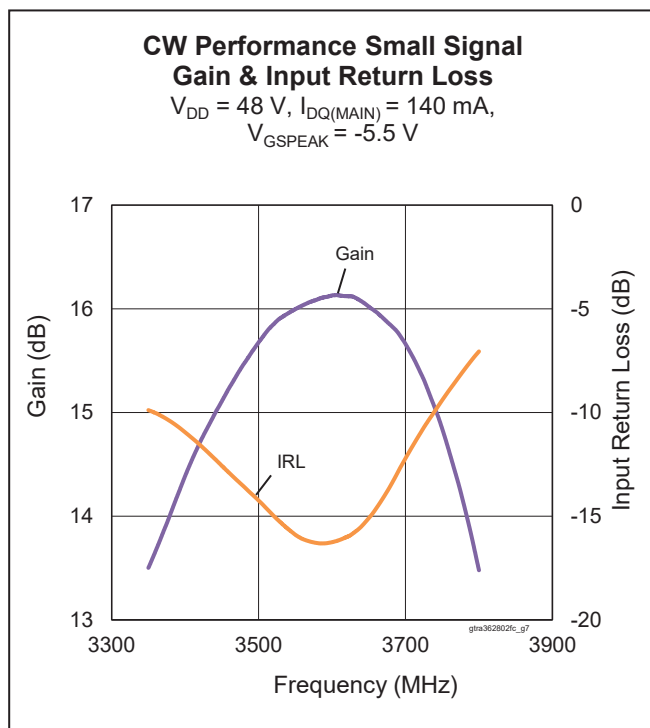
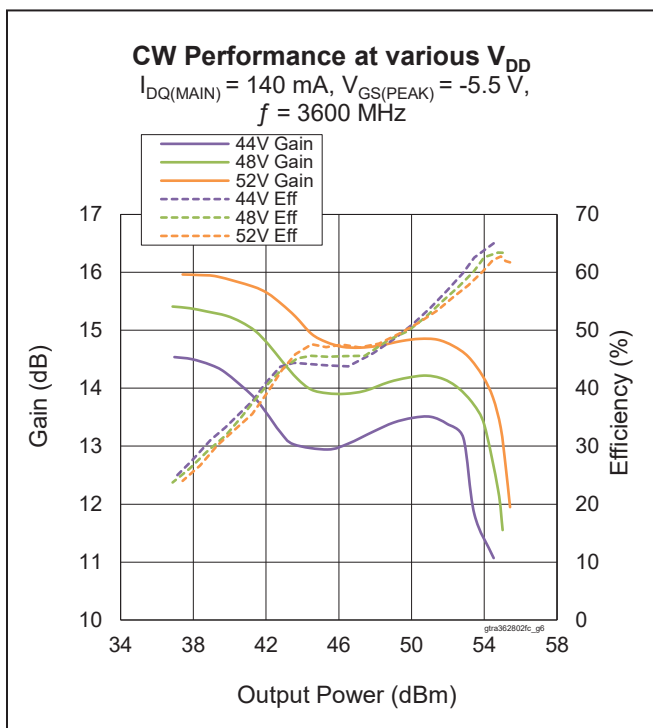
Ordering Information

Type and Version	Order Code	Package	Shipping
GTRA362802FC V1 R0	GTRA362802FC-V1-R0	H-37248C-4, earless flange	Tape & Reel, 50 pcs
GTRA362802FC V1 R2	GTRA362802FC-V1-R2	H-37248C-4, earless flange	Tape & Reel, 250 pcs

Typical Performance (data taken in production test fixture)



Typical Performance (cont.)



Load Pull Performance

Main Side Load Pull Performance – Pulsed CW signal: 10 μs , 10% duty cycle, 48 V, $I_{DQ} = 200 \text{ mA}$, class AB

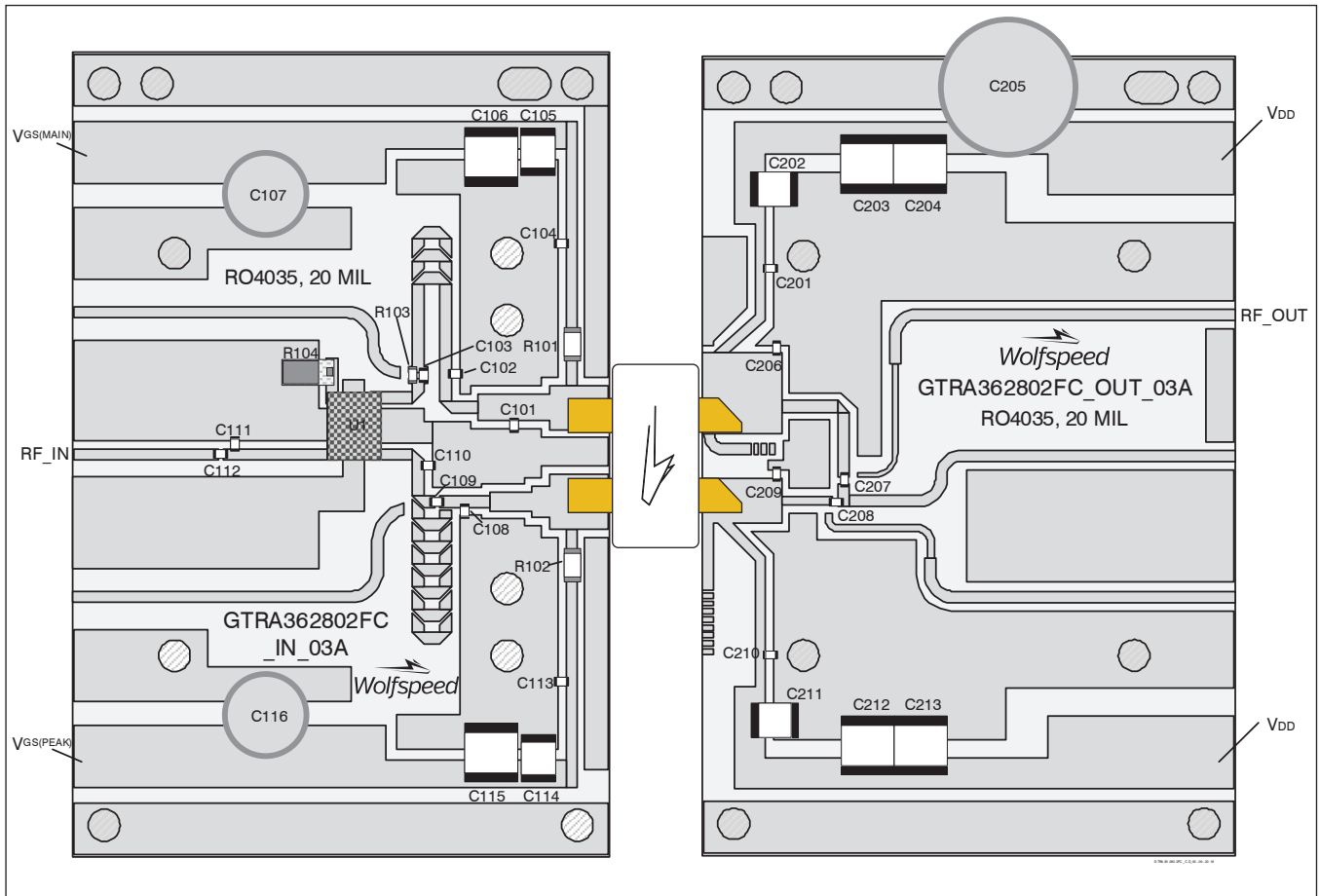
Freq [MHz]	Z_s [Ω]	P_{3dB}									
		Max Output Power					Max Drain Efficiency				
		Z_L [Ω]	Gain [dB]	P_{3dB} [dBm]	P_{3dB} [W]	η_D [%]	Z_L [Ω]	Gain [dB]	P_{3dB} [dBm]	P_{3dB} [W]	η_D [%]
3400	16+j19	5.9-j7.7	15	52.00	158.5	62.6	3.5-j4.8	16.6	50.10	102.3	74.0
3500	9.9+j11.5	9.4-j7.6	14.8	51.87	153.8	62.9	4.3-j5.2	16	50.52	112.7	71.5
3600	7.2+j6.5	7.1-j7.8	14.4	51.65	146.2	61.9	3.9-j4.7	15.9	49.70	93.3	71.6

Peak Side Load Pull Performance – Pulsed CW signal: 10 μs , 10% duty cycle, 48 V, $I_{DQ} = 140 \text{ mA}$, class AB

Freq [MHz]	Z_s [Ω]	P_{3dB}									
		Max Output Power					Max Drain Efficiency				
		Z_L [Ω]	Gain [dB]	P_{3dB} [dBm]	P_{3dB} [W]	η_D [%]	Z_L [Ω]	Gain [dB]	P_{3dB} [dBm]	P_{3dB} [W]	η_D [%]
3400	11.2-j9.2	3.9-j6.7	16	53.84	242.1	60.0	2.5-j4.8	17.8	52.30	170	71.0
3500	7.6-j8.6	3.8-j7.2	16.1	53.73	236.1	58.7	2.7-j5.2	17.9	52.35	171.8	70.0
3600	5.7-j9.5	4.6-j6.8	16.1	53.82	241	62.1	3.3-j4.8	17.1	52.60	182	68.6



Reference Circuit, 3400 – 3600 MHz



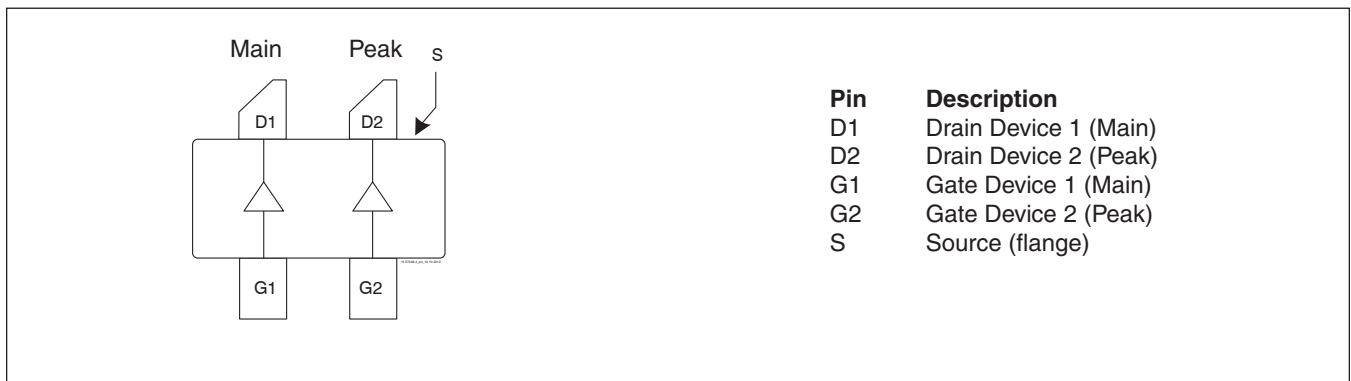
Reference circuit assembly diagram (not to scale)

Reference Circuit (cont.)**Reference Circuit Assembly**

DUT	GTRA362802FC V1
Test Fixture Part No.	LTA/GTRA362802FC-V1
PCB	Rogers 4350, 0.508 mm [0.020"] thick, 2 oz. copper, $\epsilon_r = 3.66$, $f = 3400 - 3600$ MHz
Find Gerber files for this test fixture on the Wolfspeed Web site at www.wolfspeed.com/RF	

Components Information

Component	Description	Manufacturer	P/N
Input			
C101	Capacitor, 1.3 pF	ATC	ATC800A1R3CT250T
C102, C108	Capacitor, 0.5 pF	ATC	ATC800A0R5CT250T
C103, C104, C109, C112, C113	Capacitor, 12 pF	ATC	ATC800A120JT250T
C105, C114	Capacitor, 1 μ F	TDK Corporation	C4532X7R2A105M230KA
C106, C115	Capacitor, 100 V, 10 μ F	TDK Corporation	C5750X7S2A106M230KB
C107, C116	Capacitor, 100 μ F	Panasonic Electronic Components	EEE-FP1V101AP
C110	Capacitor, 0.3 pF	ATC	ATC800A0R3CT250T
C111	Capacitor, 0.2 pF	ATC	ATC800A0R2CT250T
R101, R102	Resistor, 5.6 ohms	Panasonic Electronic Components	ERJ-8RQJ5R6V
R103	Resistor, 10 ohms	Panasonic Electronic Components	ERJ-3GEYJ100V
R104	Resistor, 50 ohms	Richardson	C16A50Z4
U1	Hybrid coupler	Anaren	XC3500P-03S
Output			
C201, C208, C210	Capacitor, 12 pF	ATC	ATC800A120JT250T
C202, C211	Capacitor, 1 μ F	TDK Corporation	C4532X7R2A105M230KA
C203, C204, C212, C213	Capacitor, 100 V, 10 μ F	TDK Corporation	C5750X7S2A106M230KB
C205	Capacitor, 220 μ F	Panasonic Electronic Components	ECA-2AHG221
C206, C209	Capacitor, 0.4 pF	ATC	ATC800A0R4CT250T
C207	Capacitor, 15 pF	ATC	ATC800A150JT250T

Pinout Diagram (top view)

Package Outline Specifications

